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		MAKITA et al.	
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		September 22, 2000	2812
(Use several sheets if necessary)			

## **FOREIGN PATENT DOCUMENTS**

**OTHER DOCUMENTS (including Author, Title, Date, Pertinent pages, etc.)**

**Ph** Lee et al, "Fabrication of High-Mobility p-Channel Poly-Si Thin Film Transistors by Self-Aligned Metal-Induced Lateral Crystallization", IEEE Electron Device Letters, vol. 17, no. 8, August 1996, pp. 407-409

**Ph** Bhat et al, "The Effects of MIC/MILC Interface on the Performance of MILC-TFTs", Device Research Conf., 1998, pp. 110-111

**Ph** Jin et al, "Performance of Thin-Film Transistors with Ultrathin Ni-MILC Polycrystalline Silicon Channel Layers" IEEE Election Device Letters, vol. 20, no. 4, April 1999, pp. 167-169

\*Examiner *Dle* Date Considered NOV-03

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**Examiner:** Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to application.

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